Phonon calculation in a crystal using DFPT Project 8 - CH-452

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Phonons: overview

- Oscillations of atomic structure in a crystal
- Harmonic oscillators: $\propto e^{i(qR+\Omega(q)t)}$
- Dispersion relation: Ω(q)

Phonon types:

- In phase: acoustic phonons, $\Omega(q=0)=0$.
- Out of phase: optical phonons, $\Omega(q=0) \neq 0$.

DOS (density of states)

$$D(\Omega) = rac{V}{V_q} rac{1}{v_g(\Omega)}, \quad v_g(\Omega) = rac{\partial \Omega}{\partial q}$$





System description [get,]

The potential involves all coulomb interactions:

$$V(r,R) = V_{nn}(R) + V_{ne}(r,R) + V_{ee}(r)$$

r electron positions, R nuclei positions.

$$i\hbar\frac{\partial\Phi}{\partial t}(r,R;t) = \left(-\sum_{I}\frac{\hbar^{2}}{2M_{I}}\frac{\partial^{2}}{\partial^{2}R_{I}} - \sum_{i}\frac{\hbar^{2}}{2m}\frac{\partial^{2}}{\partial^{2}r_{i}} + V(r,R)\right)\Phi(r,R;t)$$

Born-Opperheim approximation (adiabatic)

Electrons are much faster and more lightweight than nuclei:

$$\Phi(r, R; t) \approx \phi(R) \psi(r|R) e^{-\frac{i\hat{E}t}{\hbar}}$$



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System description

$$\left(-\sum_{i} \frac{\hbar^{2}}{2m} \frac{\partial^{2}}{\partial^{2} r_{i}} + V(r, R)\right) \psi(r|R) = E(R) \psi(r|R) \quad \text{electrons}$$

$$\left(-\sum_{i} \frac{\hbar^{2}}{2M_{I}} \frac{\partial^{2}}{\partial^{2} R_{I}} + E(R)\right) \phi(R) = \hat{E} \phi(R) \quad \text{nuclei}$$

We treat nuclei as classical particles, so at equilibrium forces are vanishing:

$$F_I^{\alpha} = -\frac{\partial E(R)}{\partial R_I^{\alpha}} = 0$$



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Expand E(R) around equilibrium positions until order two:

$$\sum_{J,\beta} (C_{IJ}^{\alpha\beta}(R) - M_I \omega^2 \delta_{IJ} \delta_{\alpha\beta}) U_J^{\beta}(R) = 0 \quad C_{IJ}^{\alpha\beta} = \frac{\partial^2 E(R)}{\partial R_I^{\alpha} \partial R_J^{\beta}} \quad (1)$$

a set of independent harmonic oscillators for nuclei I and coordinate α .

- $C_{ii}^{\alpha\beta}(R)$ are called inter-atomic force constants
- $U_I^{\beta}(R)$ represent the oscillation amplitudes
- This is a diagonalization problem!



Phonon dispersion relation

Taking fourier transform on eq. 1, get an equivalent formulation:

$$\sum_{t,s} (\tilde{C}_{st}^{\alpha\beta}(q) - M_s\Omega^2(q)\delta_{st}\delta_{\alpha\beta})U_t^{\beta}(q) = 0$$

Introduce a perturbation $u_s(q)$:

$$R_{I}[u_{s}](q) = R_{I} + \tau_{s} + u_{s}(q)e^{iqR_{I}}$$

$$\tilde{C}_{st}^{\alpha\beta}(q) = \sum_{R} e^{-iqR} C_{st}^{\alpha\beta} = \frac{1}{N_{c}} \frac{\partial^{2} E}{\partial u_{s}^{*}(q)\partial u_{t}(q)}$$

Evaluate $\tilde{C}_{ct}^{\alpha\beta}(a)$ using DFPT!



DFPT (density functional perturbation theory)

Introduce a perturbation $\delta V_0(\lambda)$ on the system potential V(r,R), then energy and density can be Taylor expanded:

$$E_{\lambda} = E + \lambda \frac{\partial E}{\partial \lambda} + \frac{1}{2} \lambda^{2} \frac{\partial^{2} E}{\partial^{2} \lambda} + \dots$$
$$\varrho_{\lambda} = \varrho + \lambda \frac{\partial \varrho}{\partial \lambda} + \frac{1}{2} \lambda^{2} \frac{\partial^{2} \varrho}{\partial^{2} \lambda} + \dots$$

The linear response can be evaluated as function of the perturbed potential.



DPFT (density functional perturbation theory)

Corollary of Hellmann-Feynman theorem

$$\frac{\partial^2 E}{\partial \lambda \partial \mu} = \int dr \frac{\partial V(r)}{\partial \lambda} \frac{\partial \varrho(r)}{\partial \mu} + \varrho(r) \frac{\partial^2 V(r)}{\partial \lambda \partial \mu}$$



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Corollary of Hellmann-Feynman theorem

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In practice:

- set $\lambda = u_s^{\alpha}(q)$, $\mu = u_t^{\beta}$, then find $\tilde{C}_{st}^{\alpha\beta}$.
- the unperturbed electrons' system needs to be relaxed first
- $\forall q$ the perturbed electrons' system needs to be relaxed too!



DPFT: Dielectric properties

Apply an external electric field to the system \vec{E} , then the dielectric tensor can be expressed as a linear response too:

$$\varepsilon_{\infty}^{\alpha\beta} = \delta_{\alpha\beta} + \frac{1}{N_c} \frac{\partial^2 E}{\partial \vec{E_{\alpha}} \partial \vec{E_{\beta}}}$$



Solve electrons' equation in a crystal [cas,]

Periodic boundary conditions in lattice \implies Bloch plane wave basis:

$$\psi_q^j(r) = \sum_G^{|G| < G_{max}} c_q^j(G) \cdot e^{i(q+G)r}, \quad E_{cut\psi} = \frac{\hbar^2 G_{max}^2}{2m}$$

Express the *Kohn-Sham* energy functional:

$$E[\varrho,c_q^j(G)] = (K + E_H + E_{XC} + \delta V_0 + V_{en})[\varrho,c_q^j(G)] + V_{nn}(R)$$

Constraint for $\varrho[c_q^j(G)]$ + orthonormality of $c_q^j(G)$.



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Constraint for $\rho[c_a^j(G)]$ + orthonormality of $c_a^j(G)$.

 $E[\rho, c_{\sigma}^{j}(G)]$ sums over all energy levels: set a **cutoff level** $E_{cut\rho}$. Preserve high freq. behaviour: **pseudopotentials**. [cas,]



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Setup: compute unperturbed solution (pw.x).

For a given family of reciprocal vectors $\{q\}$:

- Diagonalize perturbed electrons' equation (ph.x)
- Compute inter-atomic force constants in fourier space.



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Setup: compute unperturbed solution (pw.x).

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- Convert forces into real space (q2r.x).



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Setup: compute unperturbed solution (pw.x).

For a given family of reciprocal vectors $\{q\}$:

- Diagonalize perturbed electrons' equation (ph.x)
- Compute *inter-atomic force constants* in fourier space.
- Convert forces into real space (q2r.x).
- Diagonalize forces tensor (eq. 1) and get dispersion relation as eigenvalue (matdyn.x).



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Theory

(a) Horizontal view. (b) Vertical view.

Figure 1: Crystal structure visualization of bulk MoS₂ restricted to its primitive cell. The primitive cell is trigonal shaped. [Momma et al., 2011]



Crystal structure: parameters [Persson, 2016]

Primitive cell

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$$a = b = 3.190 \text{ Å}$$

- c = 14.879 Å
- $\alpha = \beta = 90^{\circ}$
- $\gamma = 120^{\circ}$

Atoms relative positions

		a	b	С
	Мо	0.3333	0.6667	0.25
	Мо	0.6667	0.3333	0.75
	S	0.3333	0.6667	0.8552
	S	0.3333	0.6667	0.6448
	S	0.6667	0.3333	0.3552
	S	0.6667	0.3333	0.1448



Reciprocal space and phonon calculation path [Hinuma et al., 2017]

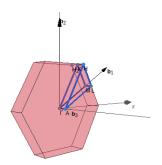


Figure 2: I^{st} brillouin zone of bulk MoS_2 (hexagonal). Γ is defined as the center.

High symmetry frequency path

$$\Gamma - M - K - \Gamma - A - L - H - A$$

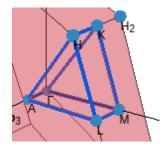


Figure 3: Path corresponding to the path described above.



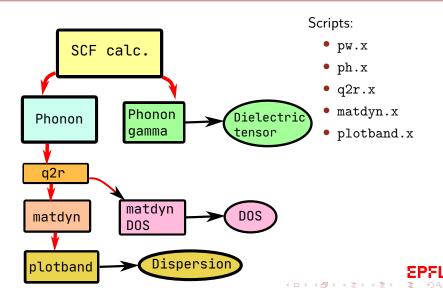
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Workflow



```
&SYSTEM
  ecutrho =
            280
  ecutwfc = 40
  ibrav = 0
 nat = 6
 nosym = .false.
 ntyp = 2
  occupations = 'smearing'
  smearing = 'cold'
 degauss = 1.46d-02
```

Electron occupation

Allow filling fraction of electrons

```
& FI.ECTRONS
```

```
conv_thr = 1.2-09
electron maxstep = 80
mixing_beta = 0.4
diago_david_ndim = 4
scf must converge = .true.
```

Energy cutoff parameters

- ecutrho: E_{cuto} [Ry].
- ecutwfc: $E_{cut\phi}$ [Ry].





Theory

```
ATOMIC SPECIES
Mο
       95.96
                Mo ONCV PBEsol -1.0.upf
S
                s pbesol v1.4.uspp.F.UPF
       32.065
ATOMIC_POSITIONS crystal
Mο
             0.33333333300
                                  0.6666666700
                                                      0.2500000000
Mο
             0.6666666700
                                 0.3333333300
                                                      0.7500000000
S
             0.6666666700
                                 0.3333333300
                                                      0.3551740000
S
             0.3333333300
                                 0.6666666700
                                                      0.8551740000
S
             0.6666666700
                                 0.3333333300
                                                      0.1448260000
S
             0.3333333300
                                 0.6666666700
                                                      0.6448260000
K POINTS {automatic}
    13 13 4 0 0 0
CELL PARAMETERS angstrom
      3.1903157000
                          0.000000000
                                              0.000000000
     -1.5951578500
                          2.7628944423
                                              0.000000000
```

0.000000000



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14.8790040000

0.000000000

mos2-bulk.phX.in

```
&inputph
  tr2_ph=1.0d-12,
  niter_ph = 70,
  prefix='mos2-bulk_',
  alpha_mix(1) = 0.4,
  ldisp=.true.,
  fildyn='<output dyn. mat.>',
  nq1=7,nq2=7,nq3=3
//
```

$\Gamma \neq 0$

- ldisp=.false.
- epsil=.true.
- Shift K_POINTS: 1 1 1

matdyn.in

```
&input
    asr='simple',
    amass(1)=95.940000d0,
    amass(2)=32.065000d0,
    flfrc='<q2r input>',
    flfrq='<output>',
    q_in_band_form=.true.,
    q_in_cryst_coord=.true.
/<<k-points integration path>
```

q2r.in

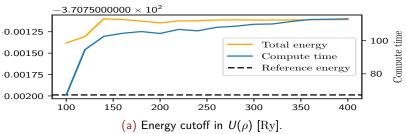
```
&input
  fildyn='<phonon input>',
  zasr='simple',
  flfrc='<output>'
```



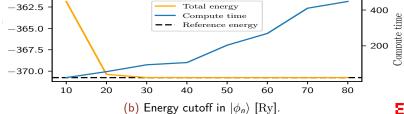
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scf calculations: convergence tests on total energy







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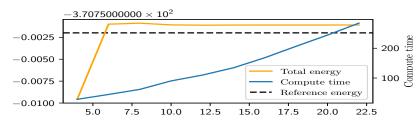


Figure 5: Number of K_POINTS discretization along (k_x, k_y) .

Advised values by QeTools

ecutrho: 280

ecutwfc: 35

K POINTS: 12

Reference energy

Increase all values at once:

 $E_{ref} = -370.7519 \text{ Ry}$



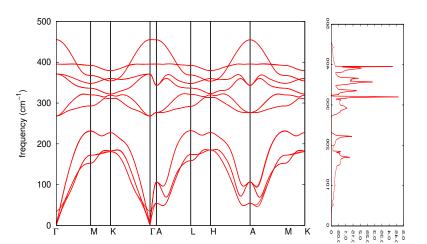


Figure 6: Dispersion relation $\Omega(Q)$ computed along the high symmetry path (frame 17). On the right the density of states (DOS).

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Dispersion relation and DOS: comparison with references

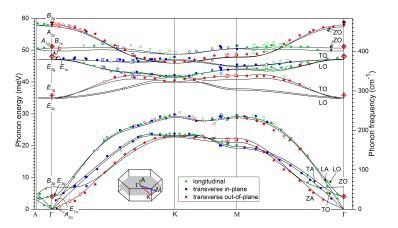


Figure 7: Dispersion relation detected with X-ray Rahman scattering [Tornatzky et al., 2018]. Each color corresponds to a direction.



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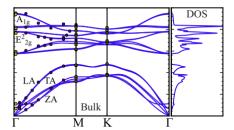


Figure 8: Dispersion relation determined by Rahman spectroscopy and a simulated curve [Molina-Sánchez et al., 2015]. Yellow points are experimental data.



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$$\varepsilon = \begin{pmatrix} 12.75 & 0 & 0\\ 0 & 12.75 & 0\\ 0 & 0 & 3.29 \end{pmatrix} \tag{2}$$

Error on ε estimation: 0.01 Absolute error with reference (fig. 9): 0.35

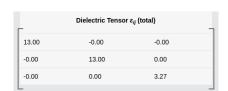


Figure 9: Reference dielectric tensor given by materials project [Persson, 2016]



- **6** Bibliography



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